NSN 5961-01-054-6496

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View Online at https://aerobasegroup.com/nsn/5961-01-054-6496 **Inclosure Material:** Metal **Overall Length:** Between 0.328 inches and 0.380 inches **Overall Diameter:** Between 0.715 inches and 0.740 inches **Internal Configuration:** Field effect **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 100.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 12.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 7.00 amperes base current, dc and 15.00 amperes collector current, dc **Power Rating Per Characteristic:** 115.0 watts total power dissipation **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: